



1N17 THRU 1N19

SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 40 Volts

Forward Current - 1.0Ampere

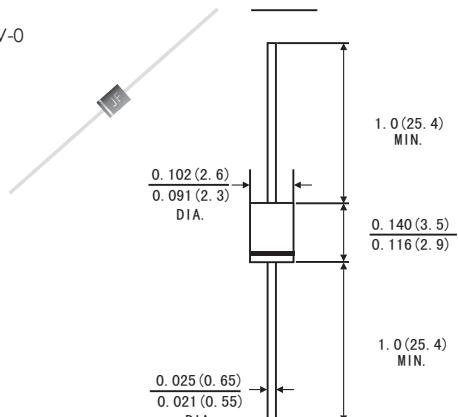
FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- High surge capability
- For use in low voltage ,high frequency inverters,free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2011/65/EU

MECHANICAL DATA

- Case: R-1 molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750,method 2026
- Polarity: color band denotes cathode end
- Mounting Position: Any
- Weight: 0.007ounce,0.20 gram

R-1



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load, derate by 20%).

	Symbols	1N17	1N18	1N19	Units
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	Volts
Maximum RMS voltage	V _{RMS}	14	21	28	Volts
Maximum DC blocking voltage	V _{DC}	20	30	40	Volts
Maximum average forward rectified current	I _(AV)		1.0		Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}		25.0		Amps
Maximum instantaneous forward voltage at 1.0 A(note 1)	V _F	0.450	0.550	0.600	Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	I _R	0.1 5			mA
Typical junction capacitance(Note 3)	C _J		110.0		
Typical thermal resistance(Note 2)	R _{θJA} R _{θJL}		50.0 15.0		°C/W
Operating junction and storage temperature range	T _J T _{STG}		-55 to +150		°C

Notes: 1.Pulse test: 300μs pulse width,1% duty cycle

2.Thermal resistance (from junction to ambient)Vertical P.C.B. mounted , 0.5"(12.7mm)lead length

3.Measured at 1.0MHz and reverse voltage of 4.0 volts

RATINGS AND CHARACTERISTIC CURVES 1N17 THRU 1N19

FIG.1-FORWARD CURRENT DERATING CURVE

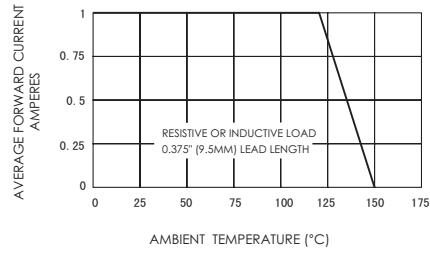


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

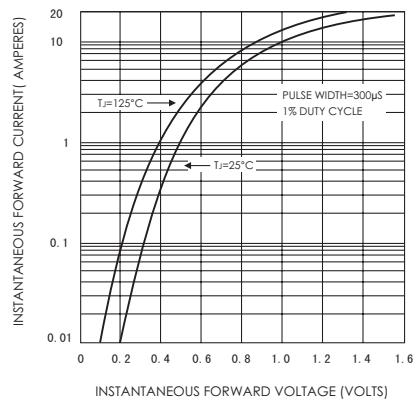
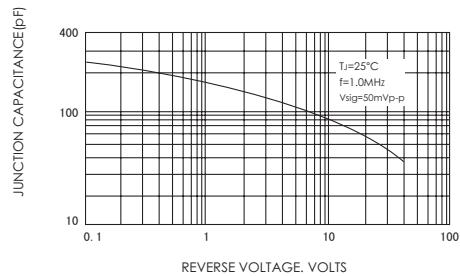


FIG.5-TYPICAL JUNCTION CAPACITANCE



JINAN JINGHENG ELECTRONICS CO., LTD.

2-2

[HTTP://WWW.JINGHENG.CN](http://WWW.JINGHENG.CN)

FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

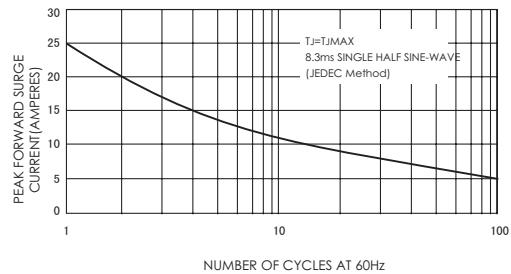


FIG.4-TYPICAL REVERSE CHARACTERISTICS

